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PNP

MJ21195

MJ21196

*Motorola Preferred Device

Silicon Power Transistors

The MJ21195 and MJ21196 utilize Perforated Emitter technology and are specifically designed for high power audio output, disk head positioners and linear applications.

- Total Harmonic Distortion Characterized
- High DC Current Gain $-h_{FE} = 25$ Min @ I_C = 8 Adc
- Excellent Gain Linearity
- High SOA: 3 A, 80 V, 1 Second





MAXIMUM RATINGS

Rating		Value	Unit
Collector–Emitter Voltage	VCEO	250	Vdc
Collector–Base Voltage	VCBO	400	Vdc
Emitter-Base Voltage	VEBO	5	Vdc
Collector–Emitter Voltage – 1.5 V	VCEX	400	Vdc
Collector Current — Continuous Peak ⁽¹⁾	IC	16 30	Adc
Base Current — Continuous	۱ _B	5	Adc
Total Power Dissipation @ T _C = 25°C Derate Above 25°C	PD	250 1.43	Watts W/°C
Operating and Storage Junction Temperature Range	T _J , T _{stg}	- 65 to +200	°C

THERMAL CHARACTERISTICS

Characteristic	Symbol	Max	Unit
Thermal Resistance, Junction to Case	R _θ JC	0.7	°C/W

ELECTRICAL CHARACTERISTICS (T_C = $25^{\circ}C \pm 5^{\circ}C$ unless otherwise noted)

Characteristic	Symbol	Min	Typical	Мах	Unit
OFF CHARACTERISTICS					
Collector–Emitter Sustaining Voltage (I _C = 100 mAdc, I _B = 0)	V _{CEO(sus)}	250	—	—	Vdc
Collector Cutoff Current ($V_{CE} = 200 \text{ Vdc}, I_B = 0$)	ICEO	_	—	100	μAdc

(1) Pulse Test: Pulse Width = 5 μ s, Duty Cycle \leq 10%.

(continued)

Preferred devices are Motorola recommended choices for future use and best overall value.

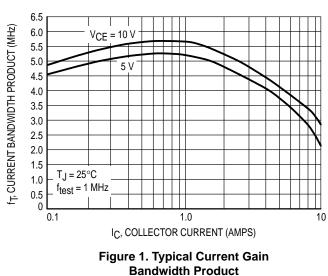


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ELECTRICAL CHARACTERISTICS (T_C = 25°C unless otherwise noted)

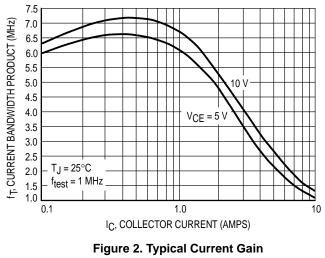
Characteristic	Symbol	Min	Typical	Max	Unit
OFF CHARACTERISTICS	1		•		•
Emitter Cutoff Current ($V_{CE} = 5 \text{ Vdc}, I_C = 0$)	IEBO	_	-	100	μAdc
Collector Cutoff Current (V _{CE} = 250 Vdc, V _{BE(off)} = 1.5 Vdc)	ICEX	—	_	100	μAdc
SECOND BREAKDOWN	•		•		-
Second Breakdown Collector Current with Base Forward Biased ($V_{CE} = 50 \text{ Vdc}, t = 1 \text{ s} (\text{non-repetitive})$ ($V_{CE} = 80 \text{ Vdc}, t = 1 \text{ s} (\text{non-repetitive})$	I _{S/b}	5 2.5			Adc
ON CHARACTERISTICS					
DC Current Gain ($I_C = 8 \text{ Adc}, V_{CE} = 5 \text{ Vdc}$) ($I_C = 16 \text{ Adc}, V_{CE} = 5 \text{ Vdc}$)	hFE	25 8		75	
Base–Emitter On Voltage (IC = 8 Adc, VCE = 5 Vdc)	V _{BE(on)}	_	-	2.2	Vdc
Collector–Emitter Saturation Voltage ($I_C = 8 \text{ Adc}, I_B = 0.8 \text{ Adc}$) ($I_C = 16 \text{ Adc}, I_B = 3.2 \text{ Adc}$)	V _{CE(sat)}			1.4 4	Vdc
DYNAMIC CHARACTERISTICS					
Total Harmonic Distortion at the Output $V_{RMS} = 28.3 \text{ V}, \text{ f} = 1 \text{ kHz}, P_{LOAD} = 100 \text{ W}_{RMS}$ hFE unmatched	T _{HD}	_	0.8	_	%
(Matched pair hFE = 50 @ 5 A/5 V) hFE matched		_	0.08	_	
Current Gain Bandwidth Product (I _C = 1 Adc, V _{CE} = 10 Vdc, f _{test} = 1 MHz)	fT	4	-	_	MHz
Output Capacitance (V _{CB} = 10 Vdc, I _E = 0, f _{test} = 1 MHz)	C _{ob}	—	-	500	pF

(1) Pulse Test: Pulse Width = 300 µs, Duty Cycle ≤2%



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Bandwidth Product

TYPICAL CHARACTERISTICS

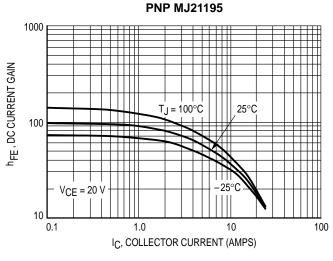


Figure 3. DC Current Gain, V_{CE} = 20 V

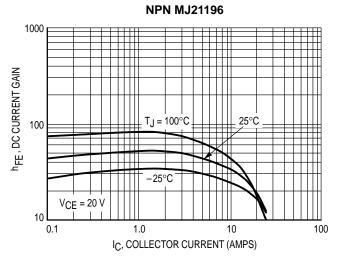


Figure 4. DC Current Gain, V_{CE} = 20 V

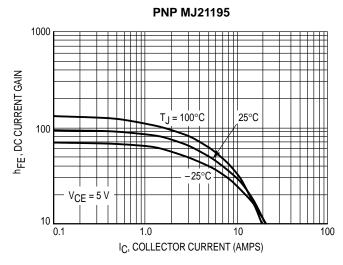


Figure 5. DC Current Gain, VCE = 5 V

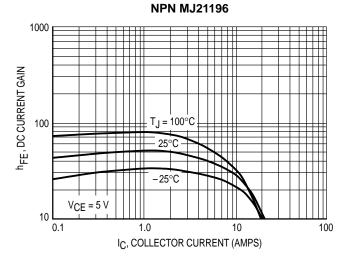
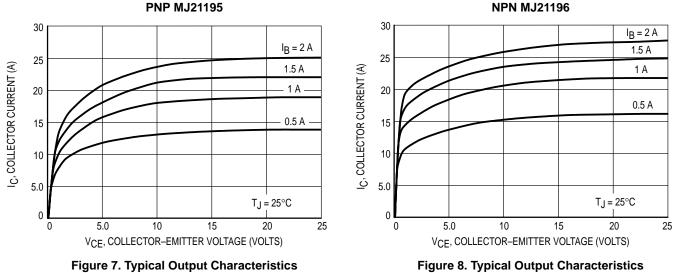


Figure 6. DC Current Gain, VCE = 5 V



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Figure 7. Typical Output Characteristics

TYPICAL CHARACTERISTICS

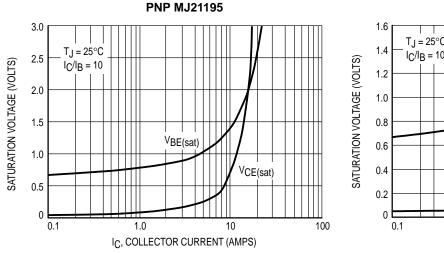
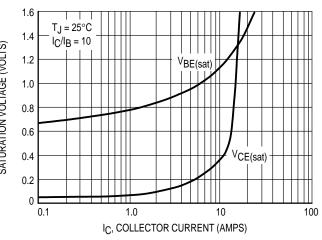


Figure 9. Typical Saturation Voltages



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Figure 10. Typical Saturation Voltages

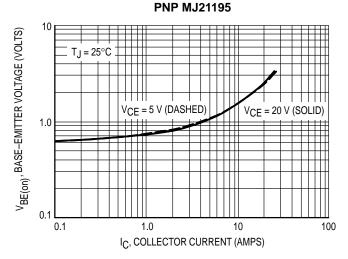


Figure 11. Typical Base–Emitter Voltage

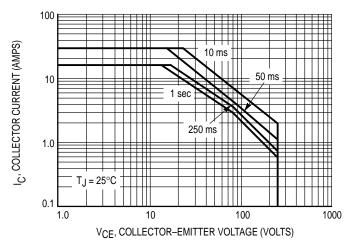


Figure 13. Active Region Safe Operating Area

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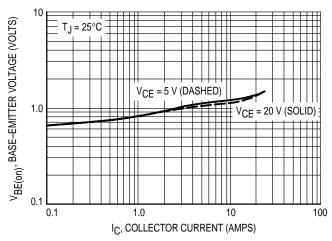


Figure 12. Typical Base–Emitter Voltage

There are two limitations on the power handling ability of a transistor; average junction temperature and secondary breakdown. Safe operating area curves indicate $I_{C} - V_{CE}$ limits of the transistor that must be observed for reliable operation; i.e., the transistor must not be subjected to greater dissipation than the curves indicate.

The data of Figure 13 is based on $T_{J(pk)} = 200^{\circ}C$; T_C is variable depending on conditions. At high case temperatures, thermal limitations will reduce the power than can be handled to values less than the limitations imposed by second breakdown.

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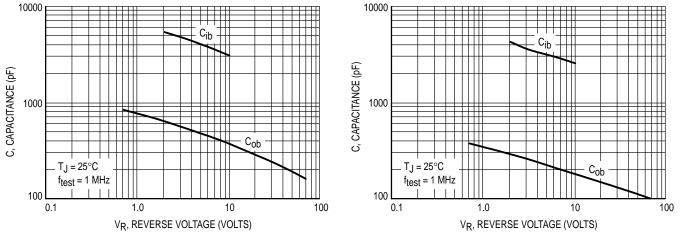
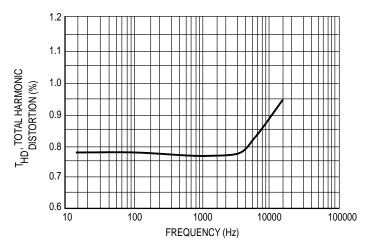


Figure 14. MJ21195 Typical Capacitance

Figure 15. MJ21196 Typical Capacitance





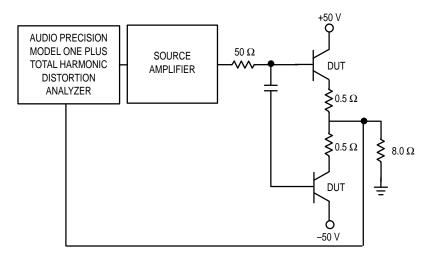
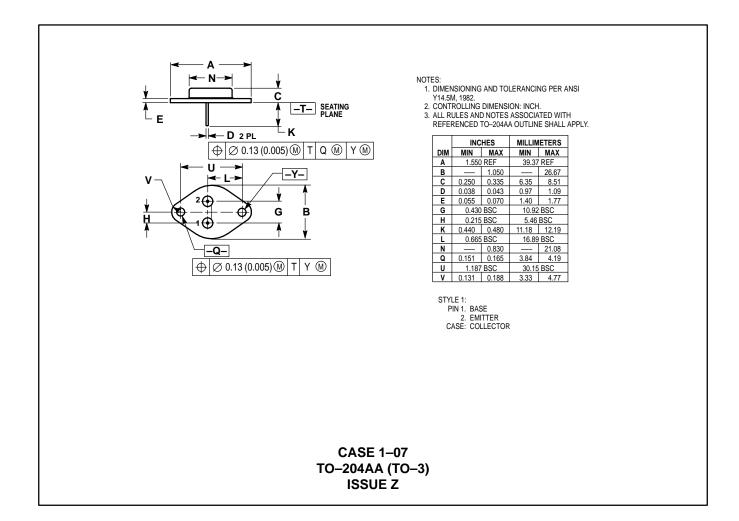


Figure 17. Total Harmonic Distortion Test Circuit

PACKAGE DIMENSIONS



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